

General Description

The AP3706 is a high performance AC/DC power supply controller for battery charger and adapter applications. The device uses Pulse Frequency Modulation (PFM) method to build discontinuous conduction mode (DCM) flyback power supplies.

The AP3706 provides constant voltage, constant current (CV/CC) regulation without requiring an opto-coupler and secondary control circuitry. It also eliminates the need of loop compensation circuitry while maintaining stability.

The AP3706 achieves excellent regulation and high power efficiency, the no-load power consumption is less than 200mW at 265VAC input.

The AP3706 is available in SOIC-8 package.

Features

- Primary Side Control for Rectangular Constant Current and Constant Voltage Output
- Eliminates Opto-Coupler and Secondary CV/CC Control Circuitry
- Eliminates Control Loop Compensation Circuitry
- Flyback Topology in DCM Operation
- Random Frequency Modulation to Reduce System EMI
- Valley Turn on of External Power NPN Transistor
- Built-in Soft Start
- Open Circuit Protection
- Over Voltage Protection
- Short Circuit Protection

Applications

- Adapters/Chargers for Cell/Cordless Phones, PDAs, MP3 and Other Portable Apparatus
- Standby and Auxiliary Power Supplies

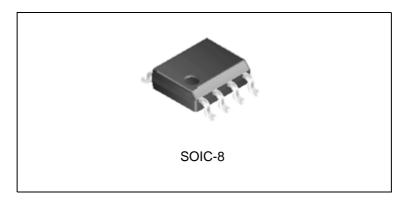


Figure 1. Package Type of AP3706



Pin Configuration

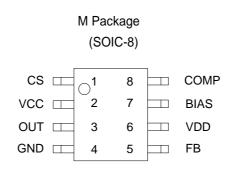


Figure 2. Pin Configuration of AP3706 (Top View)

Pin Description

Pin Number	Pin Name	Function		
1	CS	The primary current sense		
2,	VCC	Supply voltage		
3	OUT	This pin drives the base of external power NPN switch		
4	GND	Ground		
5	FB	The voltage feedback from the auxiliary winding		
6	VDD	The 5V output of the internal voltage regulator		
7	BIAS	This pin sets the bias current inside AP3706 with an external resistor to GND		
8	COMP	This pin connects a bypass capacitor for CC function		



Functional Block Diagram

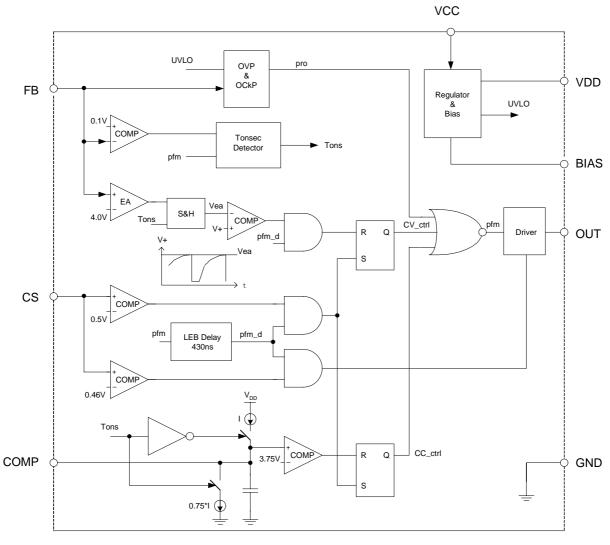
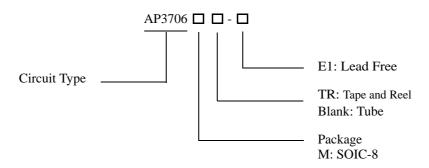


Figure 3. Functional Block Diagram of AP3706



Ordering Information



Package	Temperature Range	Part Number	Marking ID	Packing Type	
SOIC-8	-40 to 85°C	AP3706M-E1	3706M-E1	Tube	
		AP3706MTR-E1	3706M-E1	Tape & Reel	

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant.

Absolute Maximum Ratings (Note 1)

Parameter	Value	Unit	
Supply Voltage VCC	-0.3 to 30	V	
Voltage at CS, BIAS, OUT, VDD, COMP to GND	-0.3 to 7	V	
FB input (Pin 5)	-20 to 10	V	
Output Current at OUT	Internally limited	A	
Power Dissipation at T _A =25°C	0.657	W	
Operating Junction Temperature	150	°C	
Storage Temperature	-65 to 150	°C	
Lead Temperature (Soldering, 10s)	300	°C	
Thermal Resistance Junction-to-Ambient	190	°C/W	
ESD (Machine Model)	200	V	

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.



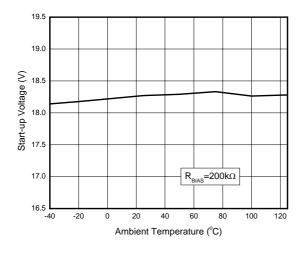
Electrical Characteristics

(V_{CC} =15V, T_A =25°C, unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
UVLO SECTION			l			
Start-up Threshold	V _{TH (ST)}		17.2	18.2	19.2	V
Minimal Operating Voltage	V _{OPR} (min)	After turn on	6.7	7.4	8.1	V
REFERENCE VOLTAGE SECTI	ON					
BIAS Pin Voltage	V _{BIAS}	R_{BIAS} =200k Ω , Before turn on	1.170	1.205	1.240	V
VDD Pin Voltage	VDD		4.75	5.0	5.25	V
STANDBY CURRENT SECTION	N			•		
Start-up Current	I _{ST}	$V_{CC} = V_{TH (ST)}$ -0.5V, R_{BIAS} =200k Ω , Before turn on		70	80	μΑ
Operating Current	I _{CC(OPR)}	R_{BIAS} =200k Ω		680	900	μΑ
DRIVE OUTPUT SECTION						
OUT Maximum Current Sink	I _{OUT}	R_{BIAS} =200k Ω	50			. mA
Source			25	30		
CURRENT SENSE SECTION						
Current Sense Threshold	V _{CS}		480	500	520	mV
Pre-Current Sense	V _{CS(PRE)}		440	460	480	mV
Leading Edge Blanking				430		ns
FEEDBACK INPUT SECTION	•					
Feedback Threshold	V_{FB}		3.90	4.00	4.10	V
Enable Turn-on Voltage	V _{FB(EN)}		-0.9	-0.7	-0.5	V
COMP THRESHOLD VOLTAGE	ESECTION		1	l	l	
Turn-on Threshold Voltage	V _{COMP}		3.42	3.60	3.78	V
PROTECTION SECTION	1	<u> </u>	J	1	1	
Over Voltage Protection	V _{FB(OVP)}		7	8	9	V



Typical Performance Characteristics



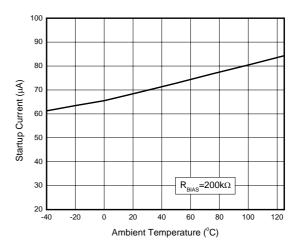
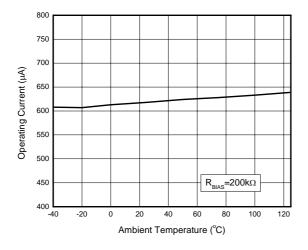


Figure 4. Start-up Voltage vs. Ambient Temperature

Figure 5. Start-up Current vs. Ambient Temperature



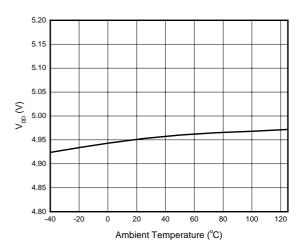
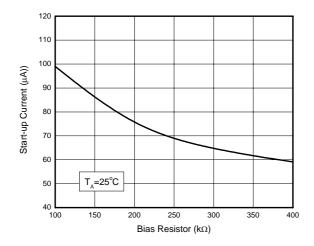


Figure 6. Operating Current vs. Ambient Temperature

Figure 7. V_{DD} vs. Ambient Temperature



Typical Performance Characteristics (Continued)



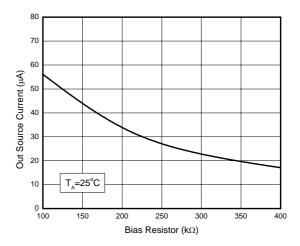


Figure 8. Start-up Current vs. Bias Resistor

Figure 9. OUT Source Current vs. Bias Resistor



Operation Description

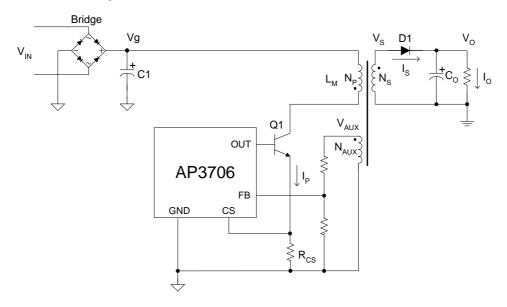


Figure 10. Simplified Flyback Converter Controlled by AP3706

Figure 10 illustrates a simplified flyback converter controlled by AP3706.

Constant Primary Peak Current

The primary current ip(t) is sensed by a current sense resistor R_{CS} as shown in Figure 10.

The current rises up linearly at a rate of:

$$\frac{dip(t)}{dt} = \frac{vg(t)}{L_{\rm M}} \qquad \dots (1)$$

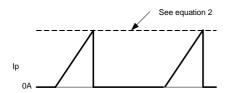


Figure 11. Primary Current Waveform

As illustrated in Figure 11, when the current ip(t) rises up to Ipk, the switch Q1 turns off. The constant peak current is given by:

$$Ipk = \frac{Vcs}{Rcs} \qquad \dots (2)$$

The energy stored in the magnetizing inductance LM each cycle is therefore:

$$Eg = \frac{1}{2} \cdot L_M \cdot Ipk^2 \qquad \dots (3)$$

So the power transferring from the input to the output is given by:

$$P = \frac{1}{2} \cdot L_M \cdot Ipk^2 \cdot f_{SW} \qquad \dots (4)$$

Where the fsw is the switching frequency. When the peak current Ipk is constant, the output power depends on the switching frequency fsw.

Constant Voltage Operation

The AP3706 captures the auxiliary winding feedback voltage at FB pin and operates in constant-voltage (CV) mode to regulate the output voltage. Assuming the secondary winding is master, the auxiliary winding is slave during the D1 on-time. The auxiliary voltage is given by:

$$V_{AUX} = \frac{N_{AUX}}{N_S} \cdot (Vo + Vd) \qquad \dots (5)$$

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Operation Description (Continued)

Where the Vd is the diode forward drop voltage.

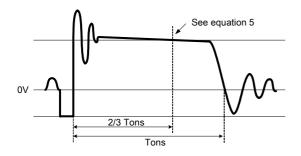


Figure 12. Auxiliary Voltage Waveform

The output voltage is different from the secondary voltage in a diode forward drop voltage. The diode drop voltage depends on the current. If the secondary voltage is always detected at a constant secondary current, the difference between the output voltage and the secondary voltage will be a fixed Vd. The voltage detection point is at two-thirds of the D1 on-time. The CV loop control function of AP3706 then generates a D1 off-time to regulate the output voltage.

Constant Current Operation

The AP3706 is designed to work in constant-current (CC) mode. Figure 13 shows the secondary current waveforms.

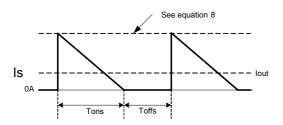


Figure 13. Secondary Current Waveform

In CC operation, the CC loop control function of AP3706 will keep a fixed proportion between D1 ontime Tons and D1 off-time Toffs by discharging or charging the capacitance connected in COMP pin. The fixed proportion is

$$\frac{Tons}{Toffs} = \frac{4}{3} \qquad \dots (6)$$

The relationship between the output constant-current and secondary peak current Ipks is given by:

$$Iout = \frac{1}{2} \cdot Ipks \cdot \frac{Tons}{Tons + Toffs} \quad \dots (7)$$

At the instant of D1 turn-on, the primary current transfers to the secondary at an amplitude of:

$$Ipks = \frac{N_P}{N_S} \cdot Ipk \qquad(8)$$

Thus the output constant-current is given by:

$$Iout = \frac{1}{2} \cdot \frac{N_P}{N_S} \cdot Ipk \cdot \frac{Tons}{Tons + Toffs} = \frac{2}{7} \cdot \frac{N_P}{N_S} \cdot Ipk$$
....(9)

Leading Edge Blanking

When the power switch is turned on, a turn-on spike will occur on the sense-resistor. To avoid false-termination of the switching pulse, a 430ns leading-edge blanking is built in. During this blanking period, the current sense comparator is disabled and the gate driver can not be switched off.

CCM Protection

The AP3706 is designed to operate in discontinuous conduction mode (DCM) in both CV and CC modes. To avoid operating in continuous conduction mode (CCM), the AP3706 detects the falling edge of the FB input voltage on each cycle. If a 0.1V falling edge of FB is not detected, the AP3706 will stop switching.

OVP & OCkP

The AP3706 includes output over-voltage protection (OVP) and open circuit protection (OCkP) circuitry as shown in Figure 14. If the voltage at FB pin exceeds 8V, 100% above the normal detection voltage, or the -0.7V falling edge of the FB input can not be monitored, the AP3706 will immediately shut off and enters hiccup mode. The AP3706 sends out a fault detection pulse every 8ms in hiccup mode until the fault has been removed.

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Operation Description (Continued)

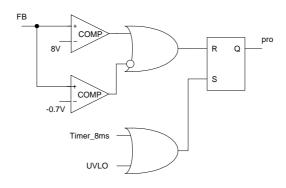


Figure 14. OVP and OCkP Function Block

Typical Application

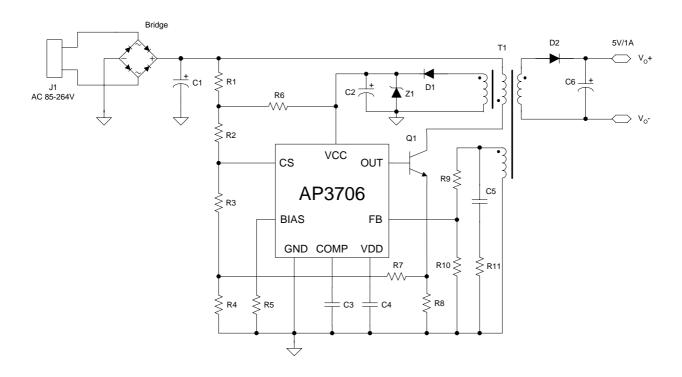
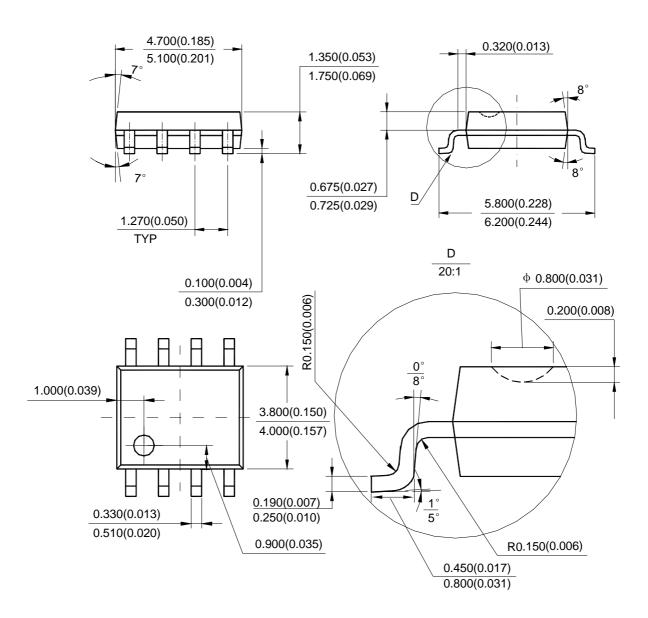


Figure 15. 5V/1A Output for Battery Charger of Mobile Phone



Mechanical Dimensions

SOIC-8 Unit: mm(inch)







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